

PARAMETER	TINGS (T _{amb} = 25 °C, unless of test condition	PART	SYMBOL	VALUE	LINIT
	TEST CONDITION	PARI	STMBOL	VALUE	UNIT
INPUT			_		
Reverse voltage			V_{R}	6	V
Forward current			I _F	60	mA
Surge current			I _{FSM}	2.5	Α
Power dissipation			P _{diss}	100	mW
Derate from 25 °C				1.33	mW/°C
OUTPUT					
Dook off state valtage		IL420	V_{DRM}	600	V
Peak off-state voltage		IL4208	V_{DRM}	800	V
RMS on-state current			I _{TM}	300	mA
Single cycle surge current			I _{TSM}	3	Α
Power dissipation			P _{diss}	500	mW
Derate from 25 °C				6.6	mW/°C
COUPLER					
Isolation test voltage between emitter and detector	t = 1 s		V _{ISO}	5300	V _{RMS}
la platian registance	V _{IO} = 500 V, T _{amb} = 25 °C		R _{IO}	≥ 10 ¹²	Ω
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C		R _{IO}	≥ 10 ¹¹	Ω
Storage temperature range			T _{stg}	- 55 to + 150	°C
Ambient temperature range			T _{amb}	- 55 to + 100	°C
Soldering temperature (1)	max. ≤ 10 s dip soldering ≥ 0.5 mm from case bottom		T _{sld}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering condditions for through hole devices (DIP).

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT			•			
Forward voltage	I _F = 10 mA	V_{F}		1.16	1.35	V
Reverse current	V _R = 6 V	I _R		0.1	10	μΑ
Input capacitance	V _F = 0 V, f = 1 MHz	C _{IN}		40		pF
Thermal resistance, junction to ambient		R _{thja}		750		°C/W
OUTPUT						
Off-state current	V _D = V _{DRM} , T _{amb} = 100 °C	I _{DRM}		10	100	μA
On-state voltage	I _T = 300 mA	V_{TM}		1.7	3	V
Surge (non-repetitive), on-state current	f = 50 Hz	I _{TSM}			3	Α
Holding current		I _H		65	500	μΑ
Latching current	V _T = 2.2 V	ΙL			500	μΑ
LED trigger current	V _D = 5 V	I _{FT}		1	2	mA
Trigger current temperature gradient		$\Delta I_{FT}/\Delta T_{j}$		7	14	μΑ/°C
Critical rate of rice off state valtage	V _D = 0.67 V _{DRM} , T _j = 25 °C	dV/dt _{cr}	10 000			V/µs
Critical rate of rise off-state voltage	V _D = 0.67 V _{DRM} , T _j = 80 °C	dV/dt _{cr}	5000			V/µs
Critical rate of rise of voltage	$V_D = 230 \ V_{RMS}, \ I_D = 300 \ mA_{RMS}, \ T_J = 25 \ ^{\circ}C$	dV/dt _{crq}		8		V/µs
at current commutation	$V_D = 230 \ V_{RMS}, \ I_D = 300 \ mA_{RMS}, \ T_J = 85 \ ^{\circ}C$	dV/dt _{crq}		7		V/µs
Critical rate of rise of on-state current commutation		dl/dt _{crq}		12		A/ms
Thermal resistance, junction to ambient		R _{thja}		150		°C/W

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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION SYMBOL MIN. TYP. MAX. UN						
COUPLER							
Critical rate of rise of coupled input/output voltage	$I_T = 0 A$, $V_{RM} = V_{DM} = V_{DRM}$	dV/dt		5000		V/µs	
Capacitance (input to output)	$f = 1 \text{ MHz}, V_{IO} = 0 \text{ V}$	C _{IO}		0.8		pF	

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	PARAMETER TEST CONDITION SYMBOL MIN. TYP. MAX. UNIT							
Turn-on time	$V_{RM} = V_{DM} = V_{DRM}$	t _{on}		35		μs		

SAFETY AND INSULATION RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC68 part 1)				55/100/21			
Comparative tracking index		CTI	175		399		
V _{IOTM}			8000			V	
V _{IORM}			630			V	
P _{SO}					500	mW	
I _{SI}					250	mA	
T _{SI}					175	°C	
Creepage distance	Standard DIP-8		7			mm	
Clearance distance	Standard DIP-8		7			mm	
Creepage distance	400 mil DIP-8		8			mm	
Clearance distance	400 mil DIP-8		8			mm	
Insulation thickness	For IL4208 only		0.4			mm	

Note

• As per IEC60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

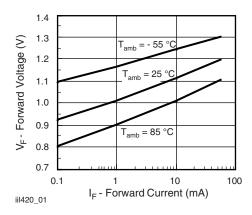


Fig. 1 - Forward Voltage vs. Forward Current

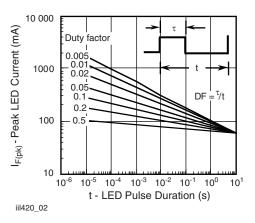


Fig. 2 - Peak LED Current vs. Duty Factor, τ

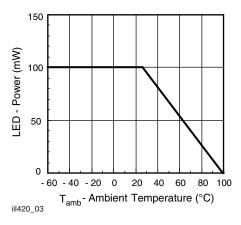


Fig. 3 - Maximum LED Power Dissipation

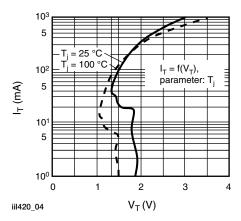


Fig. 4 - Typical Output Characteristics

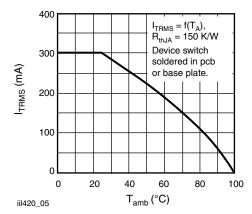


Fig. 5 - Current Reduction

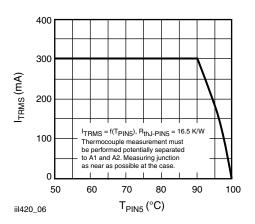


Fig. 6 - Current Reduction

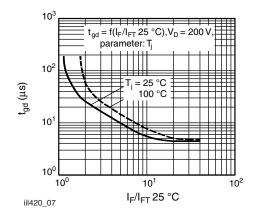


Fig. 7 - Typical Trigger Delay Time

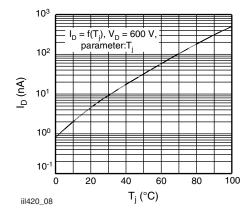
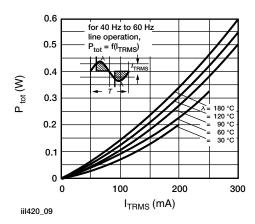
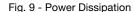


Fig. 8 - Typical Off-State Current







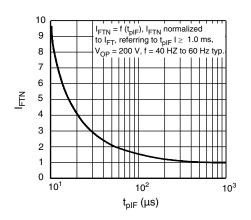
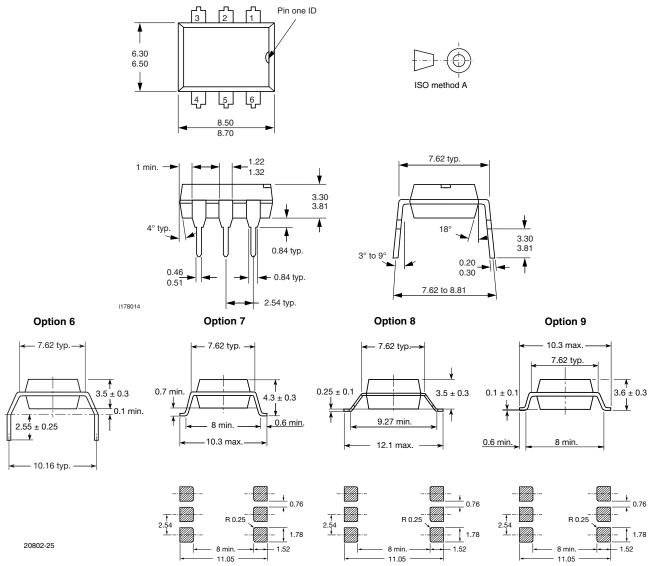


Fig. 10 - Pulse Trigger Current

PACKAGE DIMENSIONS in millimeters



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PACKAGE MARKING (example)



Notes

- Only options 1, 7, and 8 are reflected in the package marking.
- The VDE Logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.

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